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## Elevated photoelectrochemical activity of FeVO<sub>4</sub>/ZnFe<sub>2</sub>O<sub>4</sub>/ZnO branch-structures *via* slag assisted-synthesis

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Efficient recycling of industrial slag and renewable energy harvesting have become two global subjects. In this work, by recycling rare-earth oxide (REO) slag as the iron source, FeVO<sub>4</sub>/ZnFe<sub>2</sub>O<sub>4</sub>/REO (FVO/ZFO/REO) core-shell-shell nanorods (NRs) are fabricated on ZnO NRs and exhibit obviously enhanced photoelectrochemical (PEC) efficiency. The results confirm that the enhanced light absorption and conversion are attributed to the narrow band gap of ZFO. The improved electron-hole separation and charge migration can be facilitated by the cascade band alignment of ZFO, FVO and ZnO, and the branched nanotaper structures; the lifetime of the electron can be prolonged by the REO passivation layers, leading to efficient PEC enhancement. This study broadens the application of REO slag as a building block for PEC anodes and demonstrates a novel hetero-PEC anode. Overall, recycling of industrial slag could make a crucial contribution to the clean and renewable energy.

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### Introduction

Skyrocketing energy consumption and the accumulation of industrial waste have already become two serious issues, so there is an urgent need to investigate how to improve the harvesting of green energy and efficiently recycle the industrial waste. For the former issue, solar-hydrogen generation, *e.g.*, photoelectrochemical (PEC) processes, has been proven to be a highly effective strategy.<sup>1–5</sup> During the PEC reaction, electron-hole pairs can be generated as the photosensitive semiconductor absorbs photons with energy exceeding its band gap.<sup>6–8</sup> For example, n-type semiconductor BiVO<sub>4</sub> has demonstrated enhanced PEC efficiencies due to its narrow band gap of 2.4 eV as well as the very small difference between its conduction band edge and the thermodynamic potential for H<sub>2</sub> evolution.<sup>9</sup> Nonetheless, the resulting electron-hole separation and chemical stability are suboptimal. Comparatively, iron-based n-type semiconductors, such as ZnFe<sub>2</sub>O<sub>4</sub> and FeVO<sub>4</sub>, have recently emerged as promising PEC anodes due to not only their narrow band gaps and good chemical stability, but also their abundance in the earth, as well as their nontoxic and easy-to-fabricate properties.<sup>10–13</sup> Hou *et al.* have reported that the PEC activity of the anode constructed by pure TiO<sub>2</sub> nanotube arrays can be highly enhanced after the modification with ZnFe<sub>2</sub>O<sub>4</sub> *via*

an electrochemical method;<sup>14</sup> Biswas *et al.* have proven that the solar water oxidation activity experiences a notable increase with the use of W-doped FeVO<sub>4</sub> anode.<sup>15</sup> All the previous results have suggested that ZnFe<sub>2</sub>O<sub>4</sub> and FeVO<sub>4</sub> are also promising materials for PEC anode, whose performance is on par with or even better than that of BiVO<sub>4</sub>.

As for the latter issue, it is well known that how to recycle industrial waste efficiently constitutes another urgent worldwide challenge. As a typical type of industrial waste, iron slag is in plentiful amount and broad distribution. Slag is a glass-like product derived from its raw ore, and consists of a consolidated mixture of various compounds, *e.g.*, CaO, SiO<sub>2</sub>, FeO, among other materials.<sup>16</sup> Besides iron production, slag is usually used for cement production. In China's Inner Mongolia, the iron ore is commonly mixed with a large amount of rare-earth (RE) elements, such as Ce and La, making the slag rich in rare-earth oxides (REO).<sup>17</sup> Although pure RE elements can be extracted from REO slags and have irreplaceable applications, most REO slags are wasted or inefficiently utilized with minimal economic value produced. In our previous study, CaO and La<sub>2</sub>O<sub>3</sub> in REO can effectively prevent the hydrolysis of the sacrificial reagent in electrolyte, leading to enhanced PEC stability.<sup>18</sup> Considering the promising n-type iron-based materials for PEC applications and the latter issue mentioned above, major economic and social benefits could be generated by fabricating n-type iron-based materials *via* the recycling of REO slag.

In this work, branched FeVO<sub>4</sub>/ZnFe<sub>2</sub>O<sub>4</sub>/REO (FVO/ZFO/REO) core-shell-shell nanorods (NRs) are fabricated on the ZnO NRs by recycling REO slag as the iron source. The fabricated FVO/ZFO/REO NRs demonstrate an enhanced PEC efficiency, and an economic and eco-friendly characteristic. This synthetic

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strategy might be of great significance to improving the design and fabrication of future PEC iron-based photoanodes, and also creating a promising prospect concerning the economic development of REO slag.

## Experimental section

### Fabrication

(1) ZnO nanorods (NRs): an array of ZnO NRs is grown on FTO glass using a seed-assisted hydrothermal method. First, the ZnO seed layer is deposited uniformly on the native FTO glass substrate with the aid of radio-frequency (RF) magnetron sputtering. The seeded FTO glass is then dipped into a mixed electrolyte containing hexamethylenetetramine (Sigma-Aldrich, HMTA, 20 mM) and zinc nitrate hexahydrate (Sigma-Aldrich,  $\text{Zn}(\text{NO}_3)_2 \cdot 6\text{H}_2\text{O}$ , 20 mM). The deposition process typically lasts for 12 h at 90 °C; (2) rare-earth oxide (REO) powder: first, green cylindrical briquettes with a uniform diameter of 25 mm and a height of 15 mm are formed by pressing 25 g of rare-earth Bayan Obo complex iron ore (referred to as RE ore), 12.71 g of coal and 7.8 pct of water (7.8 mL water mixed with 100.0 g RE ore) into a cylindrical mold for 1 min, followed by a desiccation at 378 K for 4 h in the oven. Dry briquettes are subsequently placed into a graphite plate and heated at  $1673 \pm 5$  K for 0.5 h. Finally, the samples are rapidly removed from the furnace and subsequently cooled to ambient temperature; (3) FVO/ZFO/REO NRs: first, 20 g of REO powder is mixed into 100 mL of 70% sulfuric acid solution (nominally 95–98%  $\text{H}_2\text{SO}_4$ , Sigma-Aldrich). After stirring for 24 hours, most of  $\text{Fe}^{2+}$  ions are extracted from REO and dissolved in the suspension. Thereafter, 0.5 M sodium hydroxide solution (NaOH, Sigma-Aldrich) is added gradually to the solution with stirring until the pH value reaches 7. Thirdly, vanadium(IV) (oxy) acetylacetonate [ $\text{VO}(\text{acac})_2$ , Sigma-Aldrich] is dissolved in acetylacetone with the concentration of 0.03 M and dropped onto the top-surface of prepared ZnO NRs. Fourthly, after drying at 95 °C for 2 h, the ZnO NRs with dried  $\text{VO}(\text{acac})_2$  are dipped into the REO suspension, and then the REO suspension with ZnO NRs is irradiated by white light (solar simulator, AM 1.5 G filtered, 100  $\text{mW cm}^{-2}$ , 91160, Oriel) for 2 h. Consequently, the color of ZnO NRs is changed from green to orange. Next, after cleaning and drying, the samples are annealed in an atmosphere at 500 °C for 0.5 h. Finally, the FVO/ZFO core-shell NRs are formed by coating an REO layer, and accumulated on the top-face of ZnO NRs.

### Characterization

The morphologies of the prepared nanostructures are confirmed using a field-emission scanning electron microscope (FE-SEM, XL30S, Philips) operated with a 5.0 kV beam energy and a high-resolution scanning transmission electron microscope (HR-STEM; JEM-2200FS with Image Cs-corrector; JEOL) operated with a 200 kV beam energy.

### Measurements

(1) The optical absorbance of the samples is analyzed using a UV2501PC (Shimadzu) spectrometer with an ISR-2200

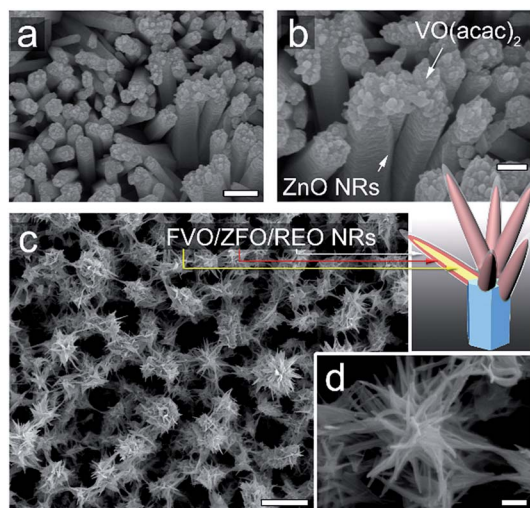
integrating sphere attachment for diffuse reflection measurements; (2) the spectra of X-ray diffractions (XRD) were measured in the range of 20–80° with a scan rate of  $4^\circ \text{ min}^{-1}$  by using the diffractometer (D/MAX-2500, Rigaku) with Cu  $K\alpha$  radiation (40 kV, 100 mA); (3) X-ray photoelectron scanning microscopy (XPS) is performed using an ESCALAB250 instrument (VG Scientific Company, USA) with Al  $K\alpha$  radiation as the excitation source; (4) IPCE tests: incident photon-to-current efficiency (IPCE) is measured using a 300 W Xe lamp (66–905, Oriel Instruments) with a monochromator (74–004, Oriel Cornerstone 130 1/8 m) whose wavelength ranges from 300 to 700 nm at an interval of 20 nm; (5) photocurrent–voltage ( $I$ – $V$ ) measurements, EIS, electron lifetime, PEC stability and Mott–Schottky tests are performed using a typical three-electrode potentiostat system (potentiostat/galvanostat, model 263A, EG&G Princeton Applied Research) with a Pt counter electrode and a saturated calomel reference electrode (SCE). The electrolyte for  $I$ – $V$  measurements, EIS, electron lifetime and PEC stability is the aqueous solution of 0.25 M  $\text{Na}_2\text{S}$  and 0.35 M  $\text{Na}_2\text{SO}_3$ , through which nitrogen is bubbled. The working electrode is illuminated from the front with a solar simulator (AM 1.5 G filtered, 100  $\text{mW cm}^{-2}$ , 91160, Oriel). Especially, the Mott–Schottky measurements are performed in the dark with a frequency of 10 kHz, and by using the aqueous solution of 0.5 M  $\text{Na}_2\text{SO}_4$ .

## Results and discussion

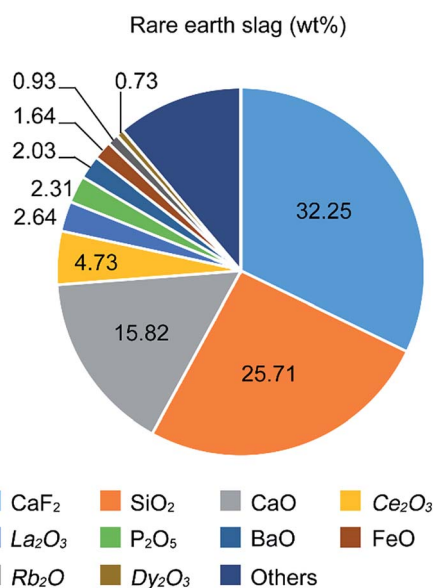
### Morphologies and growth mechanism

The morphologies evolving from the bare ZnO NRs with dried  $\text{VO}(\text{acac})_2$  to the ZnO NRs fully covered with FVO/ZFO/REO NRs are shown in Fig. 1. Fig. 1a shows that an array of ZnO NRs is distributed with high density on the FTO glass. The enlarged view in Fig. 1b exhibits that the dried  $\text{VO}(\text{acac})_2$  nanoparticles are evenly distributed on the top end of ZnO NR. For FVO/ZFO/REO NRs, a branched structure is constructed and used to fully cover the ZnO NRs (Fig. 1c). The enlarged view in Fig. 1d shows the diameters of FVO/ZFO/REO NRs are about 10–20 nm. After that, the synthesis process is carried out. Here, the major ingredients of REO slag are  $\text{CaF}_2$ ,  $\text{SiO}_2$ , CaO and REO, and the REOs are indicated with italics (Fig. 2). Only FeO with a combined amount of 1.64 wt% can be employed as iron source. Thus,  $\text{SiO}_2$  and the compounds containing Ca should be removed. The synthesis process is described as follows. First, the bare ZnO NRs are prepared *via* hydrothermal method (Fig. 3a). Next, the  $\text{VO}(\text{acac})_2$  is coated onto the top-surface of ZnO NRs and then dried (Fig. 3b). Subsequently, the REO powder is mixed into  $\text{H}_2\text{SO}_4$  solution with the concentration of 70%. So the  $\text{Fe}^{2+}$  ions could be extracted from REO and dissolved in the REO suspension (Fig. 3c). NaOH solution is then gradually dripped into the solution until the pH value increases to about 7. Fifthly, ZnO NRs with dried  $\text{VO}(\text{acac})_2$  are dipped into REO suspension and irradiated by the white light (Fig. 3d). Under the illumination, the electrons and holes are generated from the surface of ZnO. The electrons reduce the  $\text{H}^+$  ions in the water to generate  $\text{H}_2$  gas, and the holes oxidize the  $\text{Fe}^{2+}$  ions in contact with ZnO to  $\text{Fe}^{3+}$ .<sup>19</sup> During the release of  $\text{H}_2$ , the  $\text{VO}^{2+}$  in  $\text{VO}(\text{acac})_2$  is oxidized to  $\text{V}^{3+}$  and the concentration of  $\text{OH}^-$  increases in the



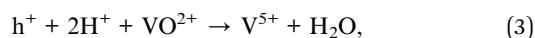
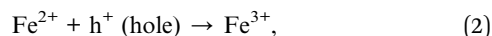
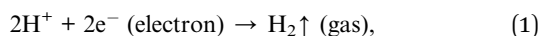


**Fig. 1** (a and b) SEM image (a) and its enlarged view (b) of the ZnO NRs decorated with VO(acac)<sub>2</sub>; (c and d) SEM image (c) and its enlarged view (d) of the FVO/ZFO/REO NRs. The scale bars are 500 nm, 200 nm, 1 μm and 100 nm for (a–d), respectively.

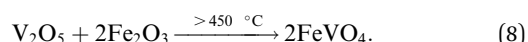
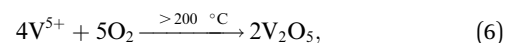
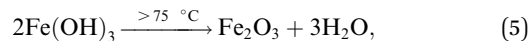


**Fig. 2** Chemical composition of rare earth slag (wt%, mass fraction).

suspension. Here, Fe<sup>3+</sup> could be reacted with OH<sup>-</sup>, thus a laminated compound containing Fe<sup>3+</sup> and REO is deposited on the ZnO NRs and the dried VO(acac)<sub>2</sub> nanoparticles (Fig. 3e). The chemical reactions involved are listed below:



After cleaning and drying, the precipitated compound assumes a porous structure (Fig. 2b and 3e). Finally, the FVO/ZFO core-shell nanopapers wrapped with a layer of REO are fabricated after annealing in the air at 500 °C (Fig. 3f).



Here, the melting points of nano-sized FVO and ZFO are lower than 600 (ref. 20) and 700 °C,<sup>21</sup> respectively. While that of REO particles is higher than 1000 °C. In our experiment, the annealing temperature is 500 °C. So the FVO and ZFO are pre-melted at 500 °C, yet REO particles does not melt and still exist in solid state. As shown in Fig. 3g, surface tension will force the REO particles migrate to the surface of ZFO structure.<sup>22</sup> Similarly, the ZFO is also formed outside the FVO. As a result, the FVO/ZFO/REO core-shell-shell structure is synthesized (Fig. 3h). Here, the FVO/ZFO core-shell NRs are only grown on the top of ZnO NRs. Because, firstly, hexagonal ZnO NR in our samples has a polar structure. The top surface is polar face and has much more defects, such as oxygen vacancies, than non-polar surfaces. So its top surface is easier to adsorb other materials than side surface. Second, Fe(OH)<sub>3</sub> precipitate could be generated *via* reaction (4) and has higher possibility to deposit on the top-surface of ZnO NRs due to the gravity. Therefore, almost all the FVO/ZFO NRs selectively deposited on the top of ZnO NR. Moreover, X-ray diffraction (XRD) measurement is carried out to explore the crystal characters of FVO and ZFO. Fig. 3i demonstrates that ZnO having hexagonal wurtzite structure and SnO<sub>2</sub> in FTO substrate are confirmed and marked with blue and pink dots, respectively. The diffraction peaks at 25.0 and 27.7 reflect (120) and (-220) faces of FVO.<sup>23</sup> Other peaks at 30.0, 35.4, 56.7 and 62.2 correspond to (220), (311), (511) and (440) faces of ZFO.<sup>24</sup> The peaks of FVO and ZFO are marked with yellow and red dots, respectively, and together confirm their well-crystalline characters.

To clearly reveal the crystal properties of the FVO/ZFO/REO NRs, TEM observation is performed. Fig. 4a shows that the FVO/ZFO/REO NRs with diameters about 10 nm share a core-shell structure. The enlarged view of Fig. 4b clearly demonstrates this core-shell morphology with the core diameter being about 3 nm, which is wrapped by a layer of REO less than 2 nm thickness. A close-up view of the boxed region in Fig. 4b is shown in Fig. 4c, which illustrates the HRTEM image indicating that the FVO/ZFO portion is a well-crystalline core-shell structure. The (120) planes of FVO<sup>20</sup> and (440) planes of ZFO are confirmed respectively by measuring the distances between crystal planes.<sup>25</sup> The FVO-ZFO core-shell structure is illustrated in Fig. 4d. The EELS element mappings in Fig. 4e–h demonstrate that Fe, V, O and Zn are evenly and accurately located at their respective positions. In our previous study, element Ca





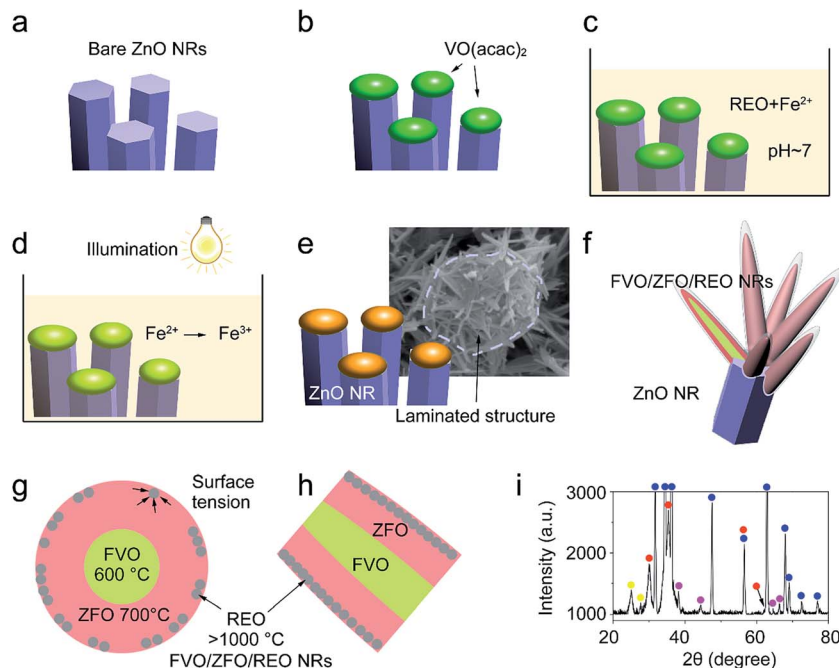


Fig. 3 (a–f) Sketch depicting key steps of fabricating ZnO NRs covered with FVO/ZFO/REO NRs; (g and h) formation mechanism of the FVO/ZFO/REO NRs; (i) XRD pattern of the FVO/ZFO/REO NRs grown on the ZnO NRs.

and La in REO can efficiently enhance the PEC performance by preventing the hydrolysis of sacrificial chemicals, such as  $\text{SO}_3^{2-}$ , in PEC electrolyte. So the mappings of Ca and La are also exhibited in Fig. 4i and j. It should be noted that the element mapping of Zn in Fig. 4h clearly confirms this core-shell structure.

In addition to the morphological observations, X-ray photoelectron spectroscopy (XPS) analysis is carried out to further study the chemical binding states of the synthesized materials. For FVO/ZFO/REO NRs, O 1s, Fe 2p, Zn 2p and V 2p are collected in Fig. 5a through Fig. 5d, respectively. *Via* deconvolution of the XPS peak, it can be seen from Fig. 5a that O 1s spectra consist of three sub-peaks due to spin-orbit coupling at 529.1, 529.7, 531.1 and 533.2 eV, corresponding to the chemical bonding of V–O,<sup>26</sup> Fe–O,<sup>27</sup> Zn–O<sup>28</sup> and O–H, respectively. Fig. 5b demonstrates that the Fe 2p spectra consist of two groups of sub-peaks due to spin-orbit coupling at the  $2p_{1/2}$  and  $2p_{3/2}$  states. For each group, it possesses three sub-peaks corresponding to octahedral and tetrahedral structures, as well as satellite peak, respectively.<sup>29,30</sup> As the binding energies of octahedral and tetrahedral structures for  $2p_{1/2}$  are very close, no deconvolution is performed here. The Zn 2p spectra in Fig. 4c also have two sub-peaks at 1022 and 1047 eV, corresponding to  $2p_{1/2}$  and  $2p_{3/2}$  states, respectively.<sup>28</sup> Similar with Zn 2p, the V 2p spectra in Fig. 5d also have two sub-peaks, corresponding to  $2p_{1/2}$  and  $2p_{3/2}$  states, respectively.<sup>26</sup> Besides, a weak V<sup>4+</sup> peak is present at 517 eV because of oxygen vacancies. The TEM and XPS measurements demonstrate that the FVO/ZFO/REO NRs are constructed by highly crystalline FVO and ZFO core-shell materials and can serve as an ideal candidate for PEC anode.

## PEC performances

To obtain enhanced PEC efficiency in this work, the light absorptions and photon-to-electron conversion efficiencies (IPCEs) of the FVO/ZFO/REO NRs under the illumination with various wavelengths are evaluated. The light absorbances of the bare ZnO NRs (black) and FVO/ZFO/REO NRs (red) are selected and compared in Fig. 6a. Bare ZnO NRs have enhanced light absorption only in UV region with the wavelength less than 400 nm, and the light absorption of the FVO/ZFO/REO NRs is enhanced in UV to visible light region. The IPCE spectra of the bare ZnO NRs (black) and FVO/ZFO/REO NRs (red) are collected and compared in Fig. 6b as the electrodes at 0 V *versus* Ag/AgCl. The IPCE value at a given wavelength can be calculated *via* the following equation:<sup>31</sup>

$$\text{IPCE}\% = \frac{I_{\text{sc}} (\text{A})}{P (\text{W})} \times \frac{1240}{\lambda (\text{nm})} \times 100, \quad (9)$$

where  $I_{\text{sc}}$  is the measured photocurrent,  $P$  is the power of the incident light at a specific wavelength, and  $\lambda$  is the wavelength of the incident light. Fig. 6b shows that, similar with the light absorbance, the IPCE curve of bare ZnO NRs shows enhancement only in the UV region due to the stronger UV photo-conversion of ZnO, while FVO/ZFO/REO NRs exhibit considerable IPCE efficiency in visible light region. For both light absorption and IPCE curves, the visible photo-conversion of ZFO is attributed to its narrow band gap of 1.9 eV and the cascade band alignment of FVO/ZFO/ZnO.

Subsequently, to understand the enhanced charge transport performance of our FVO/ZFO/REO NRs with respect to the excited electron-hole recombination, open-circuit voltage decay (OCVD) measurements are performed. Fig. 6c shows the OCVD



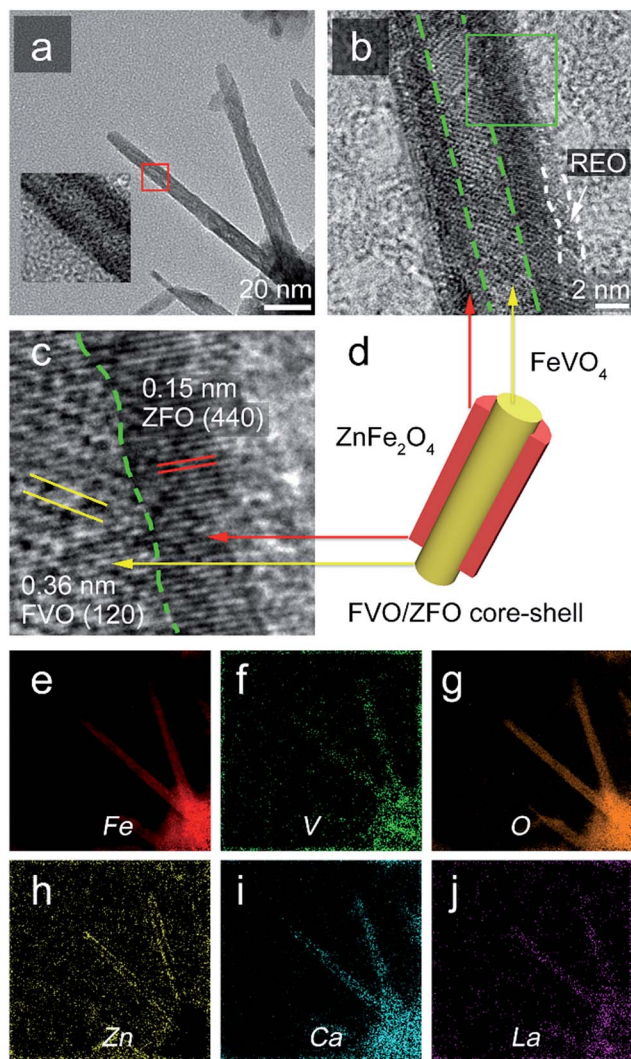


Fig. 4 (a) TEM image of the FVO/ZFO/REO NRs; (b) enlarged view taken from (a); (c) HRTEM image taken from the boxed regions in (b); (d) sketch of FVO/ZFO core-shell structure; (e–j) element mappings of Fe (e), V (f), O (g), Zn (h), Ca (i) and La (j) observed in (a).

curves of bare ZnO NRs (black) and FVO/ZFO/REO NRs (red) as a function of time. These samples are illuminated for approximately 30 s to obtain a uniform open-circuit voltage ( $V_{oc}$ ), and the  $V_{oc}$  decay is then measured with the absence of illumination. Bare ZnO NRs exhibit a faster  $V_{oc}$  decay due to the processes where holes accumulate on the surface of the ZnO NRs, and consequently the oxidation reactions involving the holes occur at the NRs/electrolyte interface. This promotes electron-hole recombination and the dissolution of ZnO. FVO/ZFO/REO NRs demonstrate better  $V_{oc}$  decay because the three-stage band alignment of ZFO/FVO/ZnO and the branched structures possess the highest light-conversion, and the photoelectron can migrate quickly through branches as pathways, leading to weaker electron-hole recombination. Besides, the passivation effect of the REO layer also slows down the  $V_{oc}$  decay. Based on the  $V_{oc}$  decay rate, the electron lifetime curves can be deduced from the following equation:<sup>32</sup>

$$\tau_n = -\frac{k_B T}{e} \left( \frac{dV_{oc}}{dt} \right)^{-1}, \quad (10)$$

where  $k_B T$  is the thermal energy,  $e$  is the positive elementary charge, and  $dV_{oc}/dt$  denotes the derivative of the open-circuit voltage transient. Fig. 6d shows the electron lifetimes  $\tau_n$  as a function of the  $V_{oc}$  of the bare ZnO NRs (black) and FVO/ZFO/REO NRs (red). The FVO/ZFO/REO NRs exhibit a longer lifetime because of their cascade band alignment, branched structures and the passivation effect of REO layer, a combination of which effectively retard the recombination of electrons and holes.

To further study the contributions of the FVO/ZFO/REO NRs to the overall PEC efficiency, electrochemical impedance spectroscopy (EIS) and photocurrent-potential ( $J-V$ ) measurements are performed subsequently. EIS provides information about the interfacial properties of electrodes. The diameter of the semicircle in EIS correlates with the electron transfer resistance, reflecting the electron transfer kinetics of the redox probe at the electrode interface. The typical EIS plots of the bare ZnO NRs (black square) and FVO/ZFO/REO NRs (red circle) in our PEC solution under illumination are shown in Fig. 7a. The EIS semicircle of the FVO/ZFO/REO NRs has a smaller diameter than that of the bare ZnO NRs, which indicates the faster charge transfer and lower charge recombination at the anode/electrolyte interface, possibly due to enhanced light absorption and photoconversion of ZFO.  $J-V$  measurements of the bare ZnO NRs (black) and FVO/ZFO/REO NRs (red) are performed under white light illumination. Fig. 7b shows that the FVO/ZFO/REO NRs have an enhanced current density of  $0.99 \text{ mA cm}^{-2}$ , which is higher than the current density of  $0.24 \text{ mA cm}^{-2}$  in bare ZnO NRs. This is due to the higher photo-conversion efficiency induced by enhanced light absorption and photo-conversion of ZFO, as well as the efficient electron-hole separation *via* cascade band alignment of ZFO, FVO and ZnO. In addition to PEC efficiency, the stability is also very important. Fig. 8 demonstrates that both of FVO/ZFO/REO NRs and bare ZnO NRs have well stabilities. It can be seen from the inset that the current density of FVO/ZFO/REO NRs is only decreased from  $0.825$  to  $0.693 \text{ mA cm}^{-2}$  with the duration of 300 min. That is the decrease is only 15%. The enhanced stability is mainly caused by the cascade band alignment of ZnO, FVO and ZFO, and the passivation layer of REO. Besides the stability test, Mott-Schottky measurements also have been carried out to evaluate the intrinsic electronic properties of the FVO/ZFO/REO NRs.<sup>33</sup> Fig. 8b shows the Mott-Schottky plots as  $1/C^2$  vs. potential ( $V$ ) for bare ZnO NRs and FVO/ZFO/REO NRs. The measurements were performed at 10 kHz. The slopes of the linear parts in Mott-Schottky plots are positive, revealing that both of the two samples are n-type semiconductors. The donor density  $N_d$  could be derived by the slope of the Mott-Schottky plot and calculated *via* the equation:  $N_d = -(2/e\epsilon_0\epsilon) \times [d(1/C^2)/dV]^{-1}$ , where  $C$  is the space charge capacitance of the semiconductor,  $e$  is the fundamental charge constant,  $\epsilon_0$  is the permittivity of the vacuum and  $\epsilon$  is the relative permittivity of the semiconductor.<sup>34</sup> Higher slope for the plot of FVO/ZFO/REO NRs demonstrates higher carrier concentration than that of



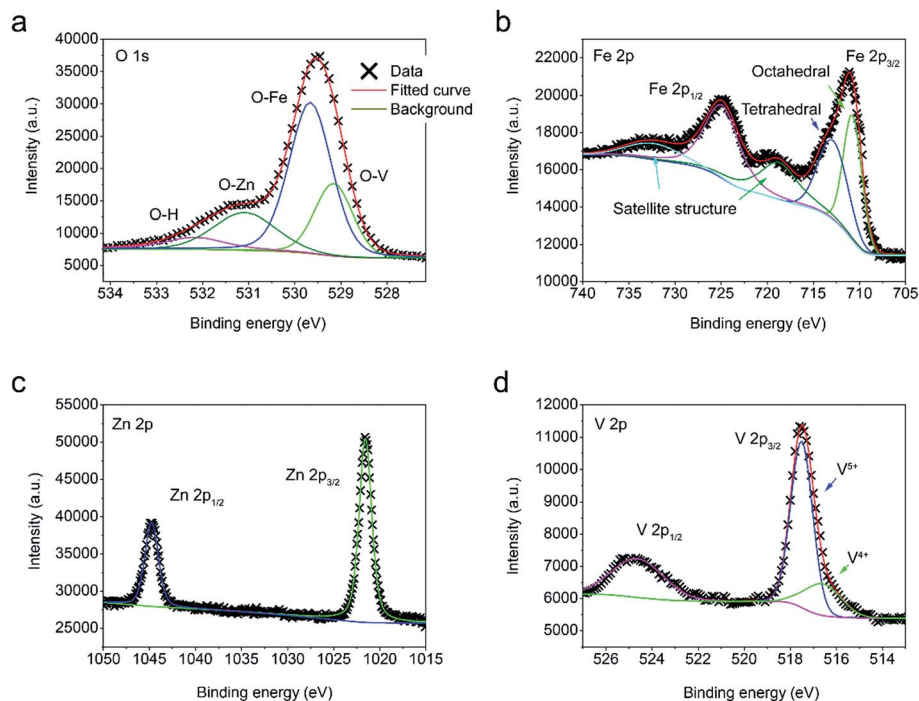


Fig. 5 (a–d) XPS spectra of O 1s (a), Fe 2p (b), Zn 2p (c) and V 2p (d) obtained from ZnO NRs decorated with FVO/ZFO/REO NRs.

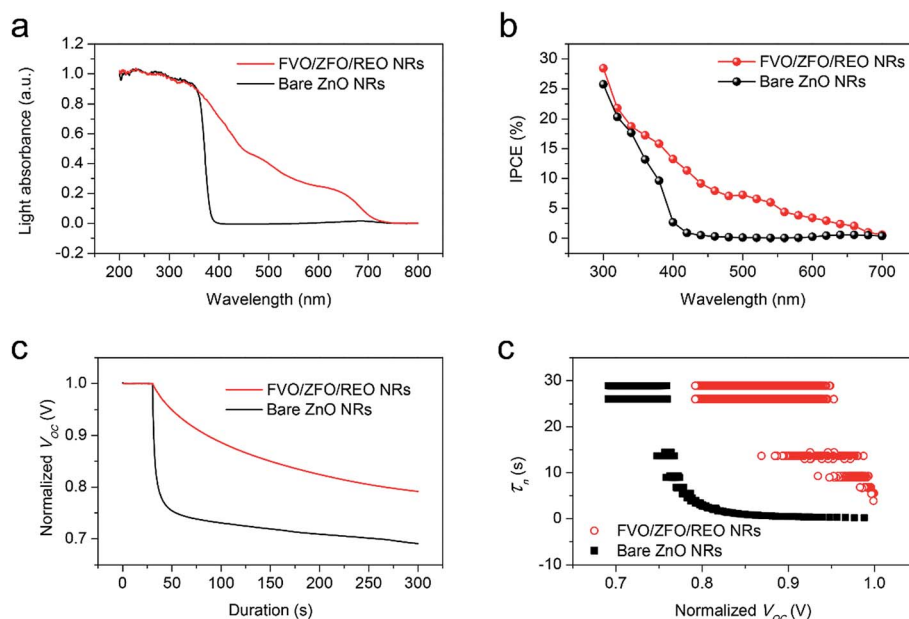


Fig. 6 (a and b) Light absorbance (a) and IPCE curves (b) of the FVO/ZFO/REO NRs (red) and bare ZnO NRs (black) as functions of wavelength; (c) electron lifetime curves as a function of the normalized  $V_{oc}$  of the photoelectrodes made of bare ZnO NRs (black) and FVO/ZFO/REO NRs (red); (d) OCVD spectra obtained from (c).

bare ZnO NRs. The flat bands ( $V_{FB}$ ) are identified as  $-0.24$  and  $-0.15$  V for bare ZnO NRs and FVO/ZFO/REO NR, respectively.

Based on the above studies and results, Fig. 9a and b exhibit schemes to explain the cascade band alignment of ZFO and ZnO, and the PEC enhancement observed for FVO/ZFO/REO NRs, respectively. Overall, a cascade band structure is constructed (Fig. 9a) as dictated by the band gaps of 1.9 eV, 2.7 eV

and 3.37 eV for ZFO, FVO and ZnO, respectively, which facilitates the transport of electrons and holes, and prevents their recombination. Under illumination, photogenerated electrons in the conduction band (CB) of ZFO are then injected into FVO and ZnO. Those electrons ultimately arrive at the Pt counter electrode to reduce the hydrogen ions to hydrogen gas (Fig. 9b). Most of the holes accumulated on the surface of the REO layers





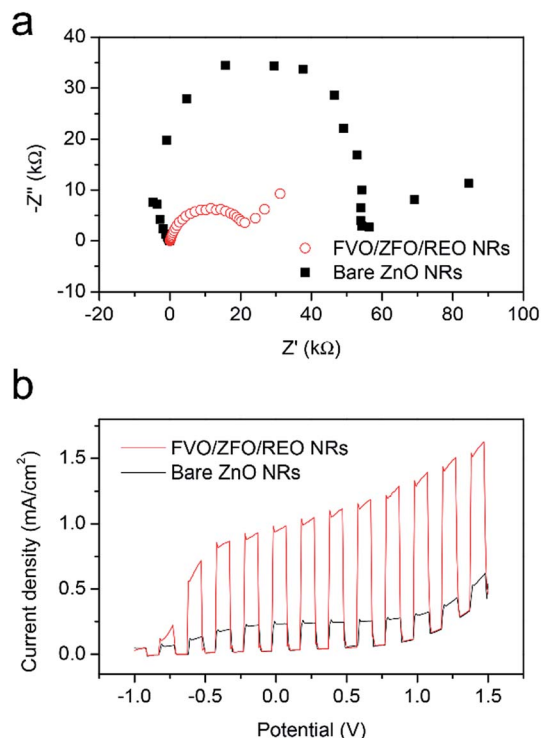


Fig. 7 (a and b) EIS plots (a) and chopped current density vs. potential ( $J-E$ ) characteristics (b) of bare ZnO NRs (black) and FVO/ZFO/REO NRs (red) under white light (AM 1.5G,  $100 \text{ mW cm}^{-2}$ ) illumination.

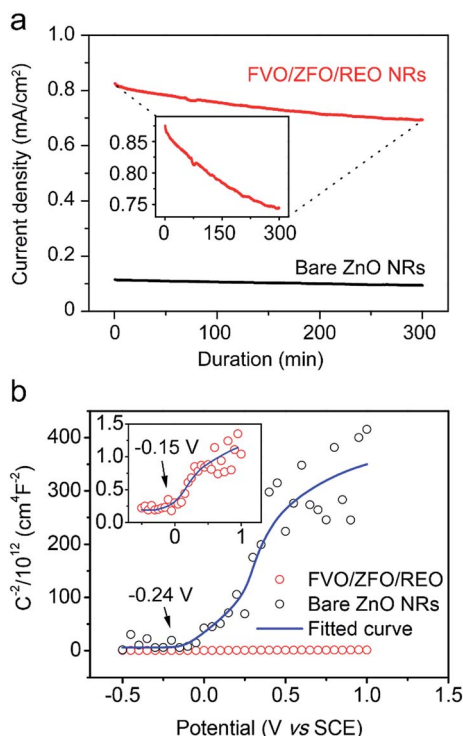


Fig. 8 (a) PEC stability tests of FVO/ZFO/REO NRs grown on ZnO NRs (red curve) and bare ZnO NRs (black curve) with duration of 300 min. The inset shows a close-up of current density of the FVO/ZFO/REO NRs; (b) Mott-Schottky plots at a fixed frequency of 10 kHz on bare ZnO NRs (black circle) and FVO/ZFO/REO NRs (red circle).

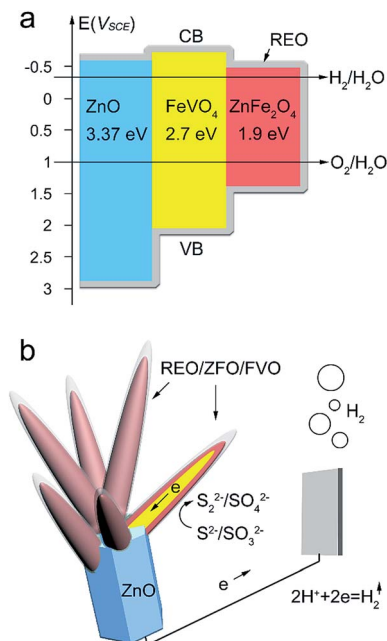


Fig. 9 (a and b) Band alignment (a) and PEC process (b) of the FVO/ZFO/REO NRs.

oxidize the  $\text{S}^{2-}$  ions to  $\text{S}_2^{2-}$  ions. The role of the sacrificial reagent in the electrolyte ( $\text{SO}_3^{2-}$ ) is to prevent a reverse reaction by reducing  $\text{S}_2^{2-}$  to  $\text{S}^{2-}$ .<sup>35</sup> For the branched structures, the large surface area can absorb more light irradiation and provide plenty of the interfacial area with electrolyte for PEC reaction. Besides, a great number of nanotapers can act as numerous pathways to facilitate the charge transfer, leading to the enhanced PEC efficiency. Our previous studies confirm that the REO can also be used as the  $\text{OH}^-$  supplier to block hydrolysis of  $\text{Na}_2\text{S}$  and  $\text{Na}_2\text{SO}_3$  in the PEC electrolyte. As a result, the PEC performance and the electron lifetime can be obviously enhanced by the FVO/ZFO/REO NRs.

## Conclusions

FVO/ZFO/REO core-shell-shell NRs are formed on the ZnO NRs by using REO powder as iron source, giving rise to efficient PEC anodes for hydrogen generation. The REO layer can tightly wrap around the VO/ZFO core-shell NRs and act as a passivation layer, leading to improved electron lifetime. Moreover, the PEC enhancement can also be ascribed to the cascade band alignment of ZFO, FVO and ZnO, and the clustered structures. The products and fabrication methods presented in the current study are highly suitable for developing various heteronanostructures for energy devices. Overall, the FVO/ZFO/REO NRs can increase the PEC efficiency obviously compared with bare ZnO NRs and demonstrate the potential application for future PEC anodes.

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